



# PHY208 – Atoms and lasers

## Lecture 7

### **Pulsed Laser Technology: Short but Powerful**

Daniel Suchet & Erik Johnson

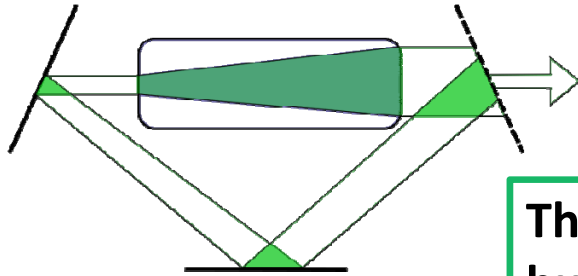
[Daniel.suchet@polytechnique.org](mailto:Daniel.suchet@polytechnique.org)

[Erik.johnson@polytechnique.edu](mailto:Erik.johnson@polytechnique.edu)

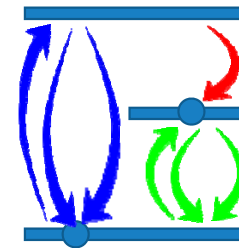
# What have we seen so far? LASER

An optical cavity (« oscillator ») → condition on phase

An amplifying medium (« gain ») → condition on ampl. / intensity



Introduced a 3 level systems.



$$r_{\text{abs}} = r_{\text{stim}} = \frac{\sigma I}{h\nu} = W$$

$$r_{\text{spont}} = \Gamma$$

**These are all steady state solutions to rate equations, but we can use these ideas to understand pulsing**

Need gain to compensate losses (output + parasitic)

Impossible in Lorentz model, requires population inversion.

$$g = \sigma_{eg} \underbrace{(n_e - n_g)}_{\Delta n}$$

Basic laser properties

$$g = \frac{g_0}{1 + I/I_{\text{sat}}}$$

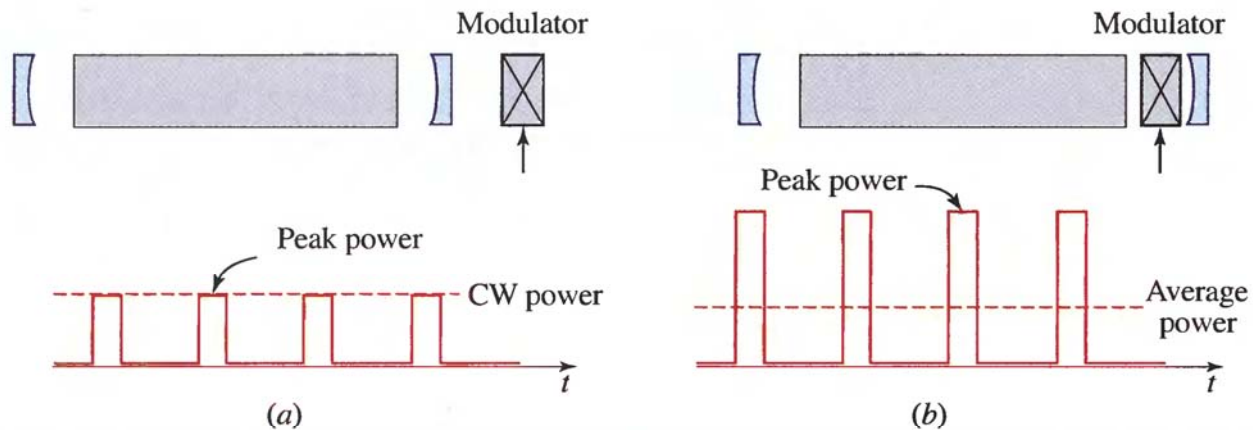
Laser threshold,  
Gain saturation,  
Steady state intensity,  
Steady state population inversion

# Why would we want to pulse a laser?

- Some lasers must be operated in a pulsed mode since CW operation cannot be sustained.
- High speed optical communications require sending HI/LO bits
- Instantaneous optical power can be greatly increased when the output pulse has a limited duration.
- Processing outcome is different when exposure causes little heating
- Short pulses can probe very fast physical processes



# External vs internal modulation



**Figure 15.4-1** Comparison of pulsed laser outputs achievable with (a) an external modulator, and (b) an internal modulator.

# Outline of Lecture

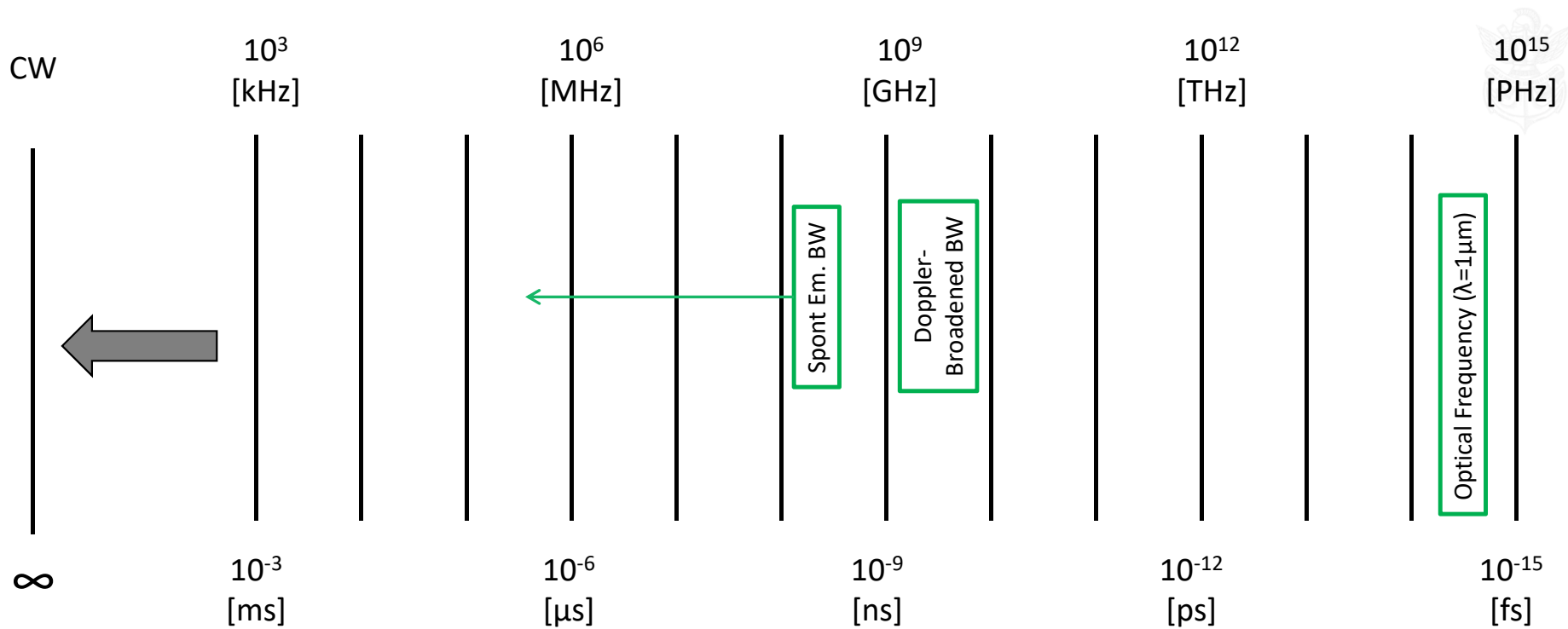


## Laser Pulsing



- I. Modulation for Telecommunications
  - Semiconductor lasers
  - Direct gain modulation
  
- II. Advanced Techniques for Shorter Pulses
  - Q-switching (and cousins)
  - Mode locking
  
- III. Even higher power
  - Chirped pulse amplification

# Time scales for laser pulsing

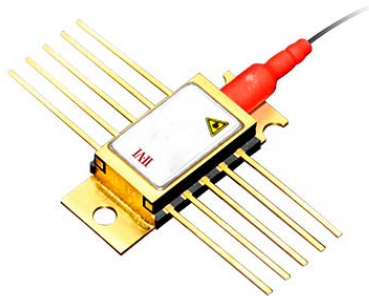
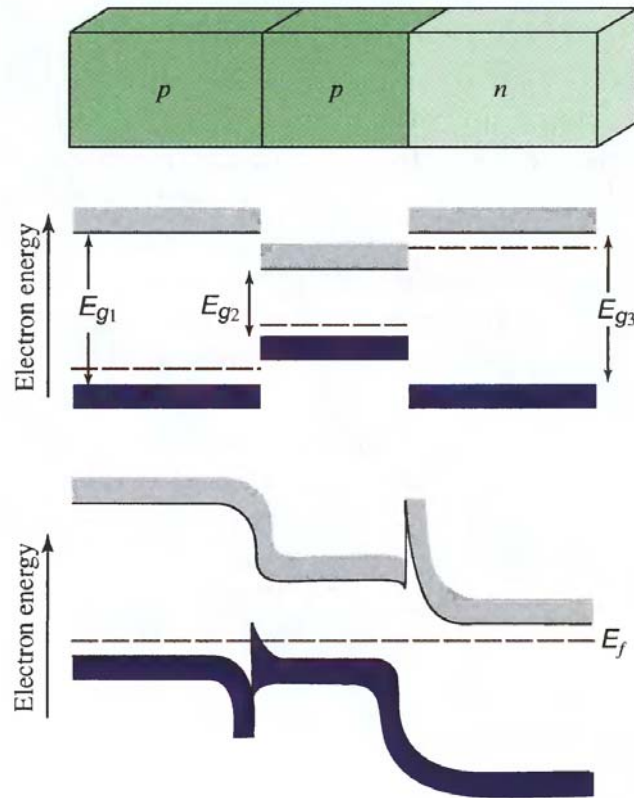
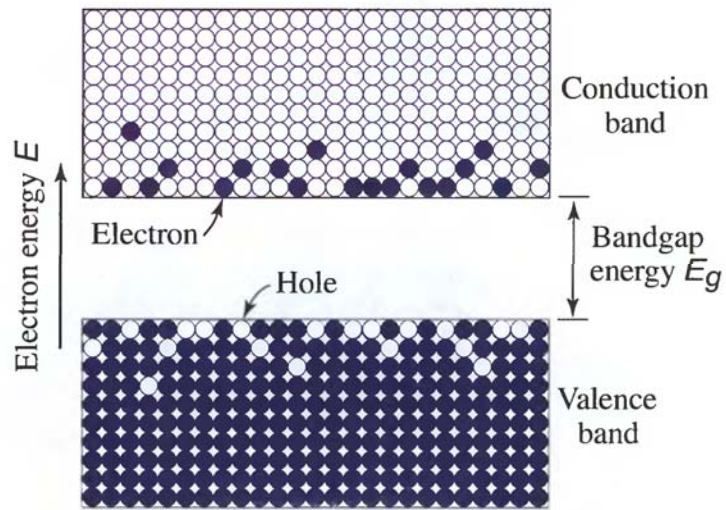


Optical frequency ( $\lambda = 1 \mu\text{m}$ )

Bandwidth due to Spontaneous Emission

Bandwidth due to Doppler Broadening

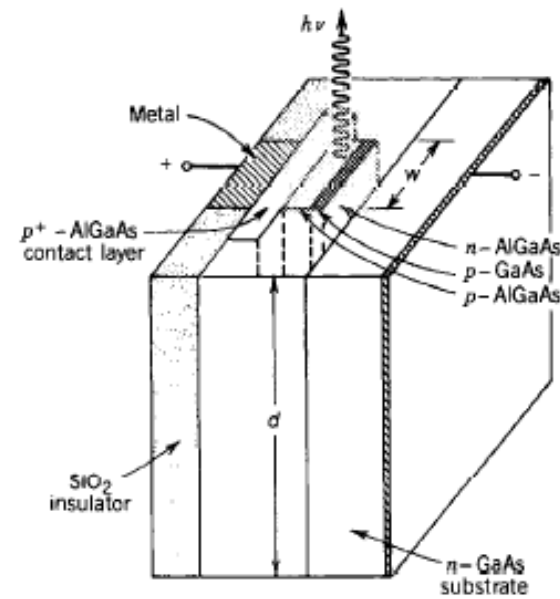
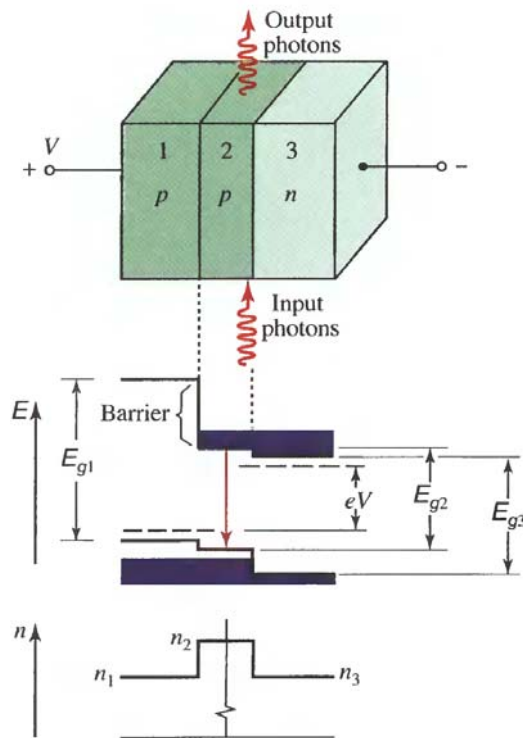
# I – Semiconductor Lasers



Applying a voltage will inject electrons from one side, and « holes » from the other side.

They accumulate and recombine in the middle.

# Localizing gain in a semiconductor laser



**Figure 16.3-7** Schematic diagram of an AlGaAs/GaAs buried-heterostructure semiconductor injection laser. The junction width  $w$  is typically 1 to 3  $\mu\text{m}$ , so that the device is strongly index guided.

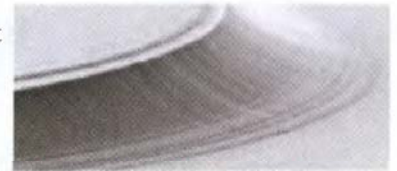
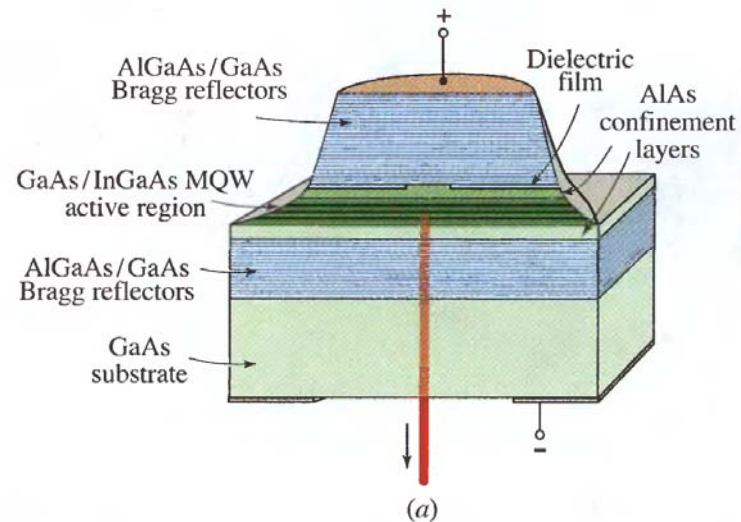
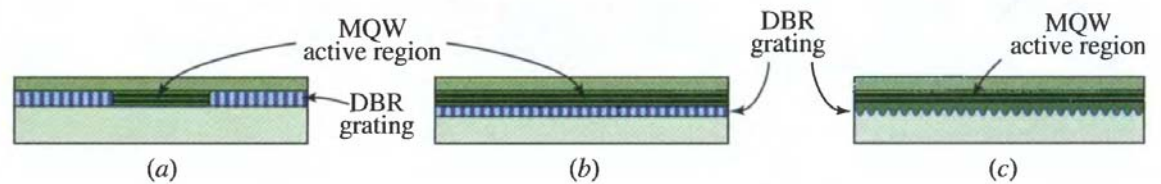


# Feedback in Semiconductor Lasers

Tricky to put a metallic mirror in place for a semiconductor layer.

Reflector may be a:

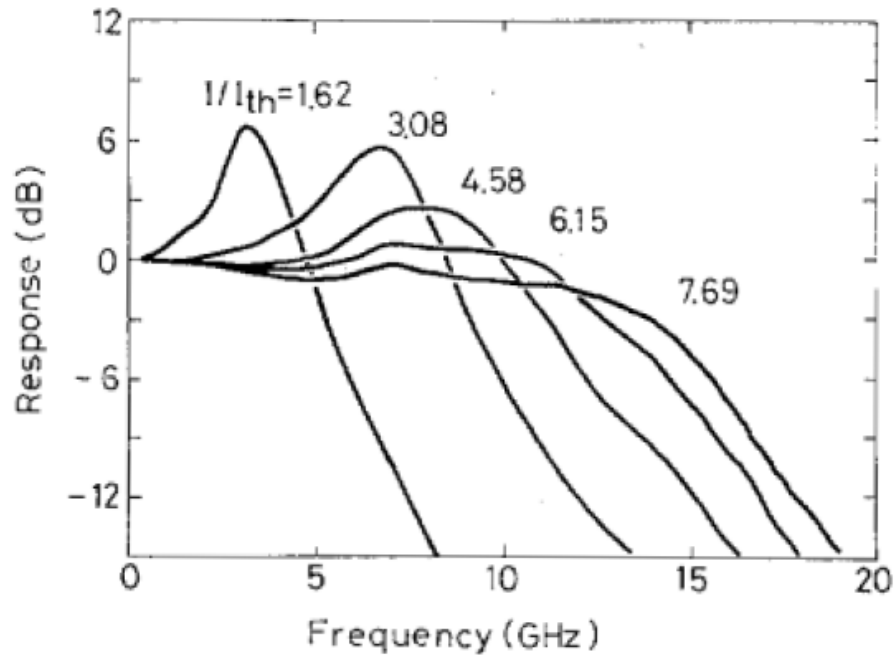
- Cleaved facet
- Distributed Bragg reflector
- Distributed Feedback (everywhere)
- In vertical cavity, surface emitting lasers, Bragg reflectors can be stacks (more reflective)
- Gain medium is shorter (need multiple quantum wells for greater gain)



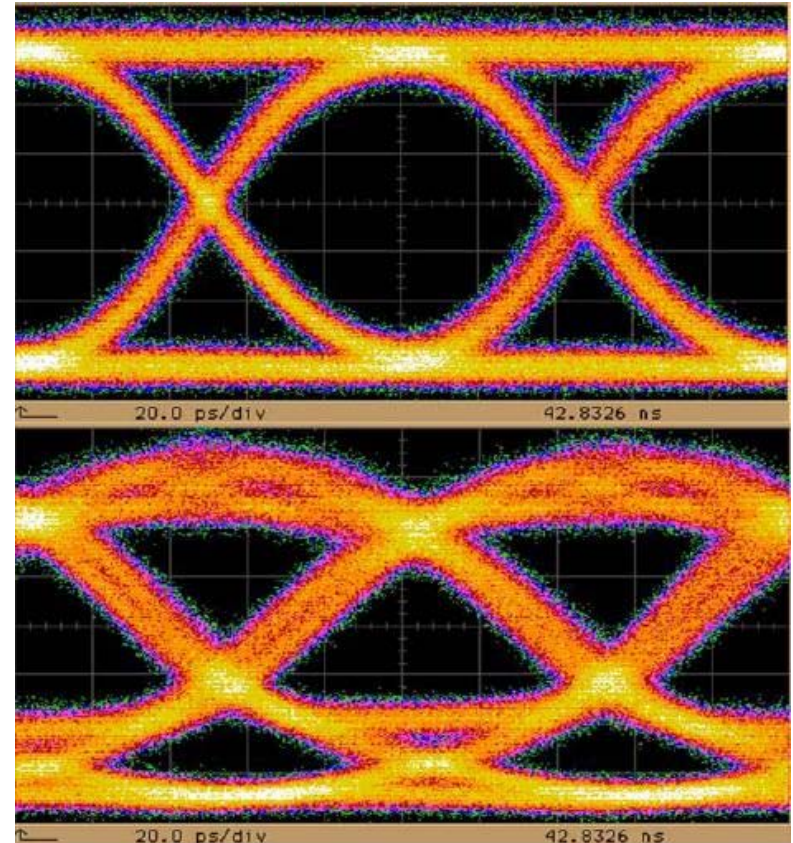
(b)

# Modulation for Optical Communication

- Semiconductor lasers are biased at some current, then modulated around a small swing

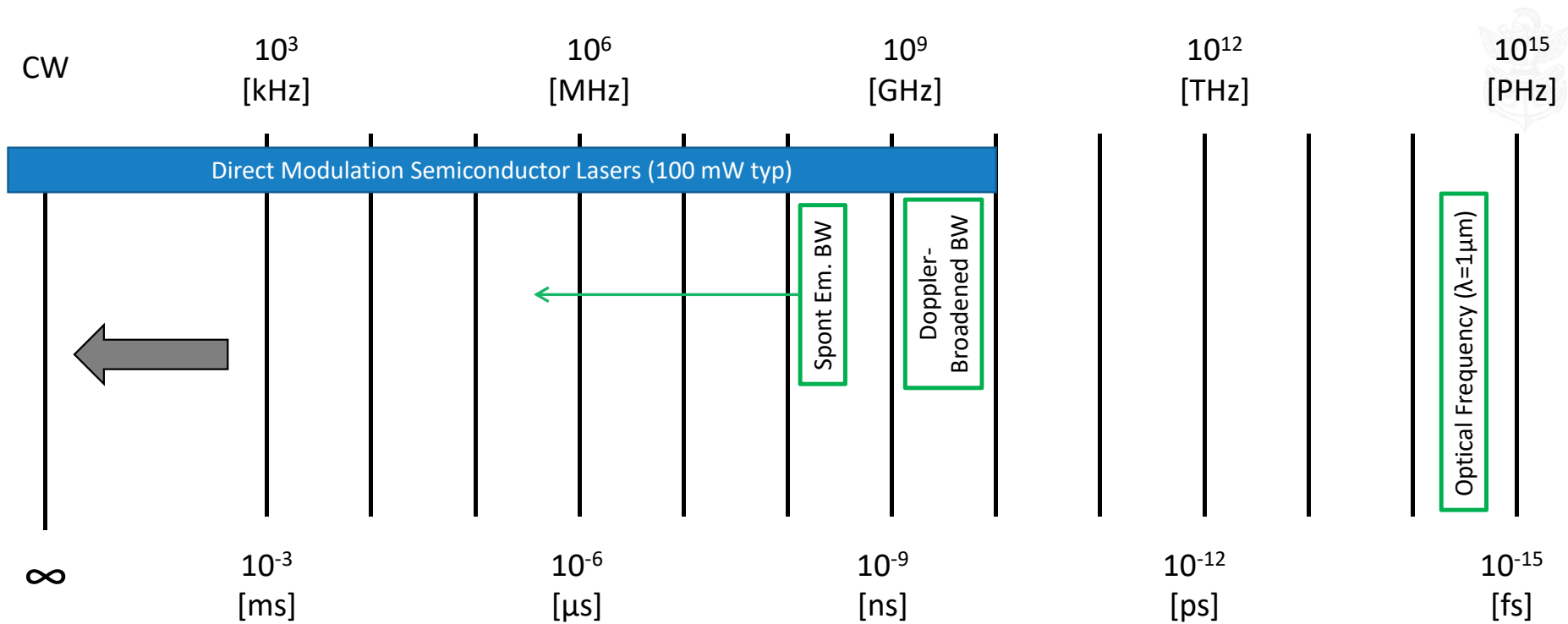


Transfer characteristic of DFB InGaAsP laser



Eye diagram showing received signal in optical telecom system

# Time scales for laser pulsing



# Outline of Lecture



## Laser Pulsing



- I. Modulation for Telecommunications
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- II. Advanced Techniques for Shorter Pulses
  - Q-switching (and cousins)
  - Mode locking
  
- III. Even higher power
  - Chirped pulse amplification

# III. Optical gain (from lecture 2)

Gain in a 3 level system :  $g = \sigma \Delta n = \frac{g_0}{1+I/I_{\text{sat}}}$  (actually, very generic form)

Unsaturated gain  $g_0 = \sigma \frac{W_p - \Gamma_{eg}}{W_p + \Gamma_{eg}} n_{\text{tot}}$  [m<sup>-1</sup>]

Saturation intensity  $I_{\text{sat}} = \frac{h\nu_L}{2\sigma_{eg}} (W_p + \Gamma_{eg})$  [W.m<sup>-2</sup>]

- Unsaturated gain increases with pumping rate ( $W_p$ ), interaction cross section ( $\sigma$ ), atomic density ( $n_{\text{tot}}$ )
- Unsaturated gain decreases with recombination rate ( $\Gamma_{eg}$ )

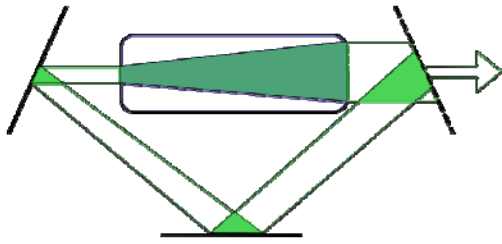
*All atoms in g state*
 $-\sigma n_{\text{tot}} \leq g_0 \leq \sigma n_{\text{tot}}$ 
*All atoms in e state*

- Gain decreases with laser intensity

At low laser intensity,  $g = g_0$

At high laser intensity,  $g \underset{I \gg I_{\text{sat}}}{\sim} g_0 \frac{I_{\text{sat}}}{I} \rightarrow 0$

# III. Laser steady-state (from lecture 2)



$$|\mathcal{E}(L)| = |\mathcal{E}(0)|$$

$$r \exp(-k''d) \exp\left(-\frac{\alpha_0 L}{2}\right) = 1$$

$$I(L) = I(0)$$

$$R \exp(-\alpha_0 L) \exp(gd) = 1$$



$$\frac{g_0 d}{1 + I/I_{\text{sat}}} = \alpha_0 L + T$$

Optical gain

Optical losses

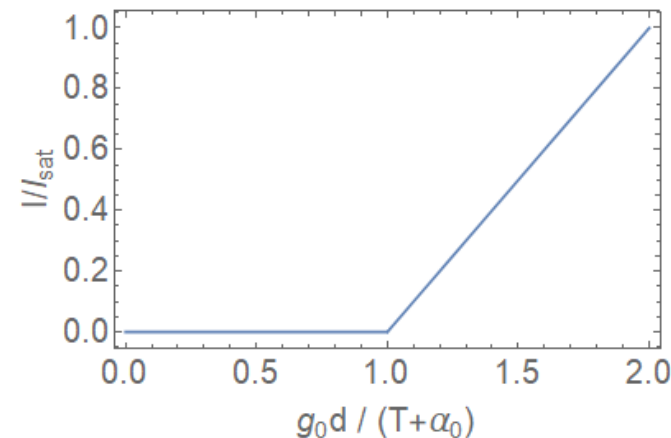
Laser intensity

$$I = I_{\text{sat}} \left( \frac{g_0 d}{T + \alpha_0 L} - 1 \right)$$

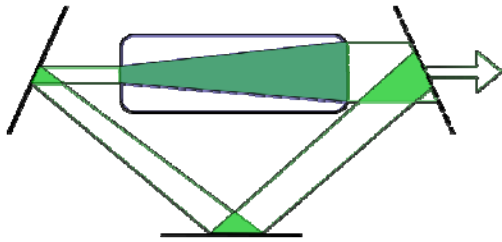
Laser intensity adjusts to unsaturated gain and losses,  
so that total gain (including saturation) = total loss

**Necessary condition for  $I > 0$  :**

Lasing threshold  $g_0 d \geq T + \alpha_0 L$



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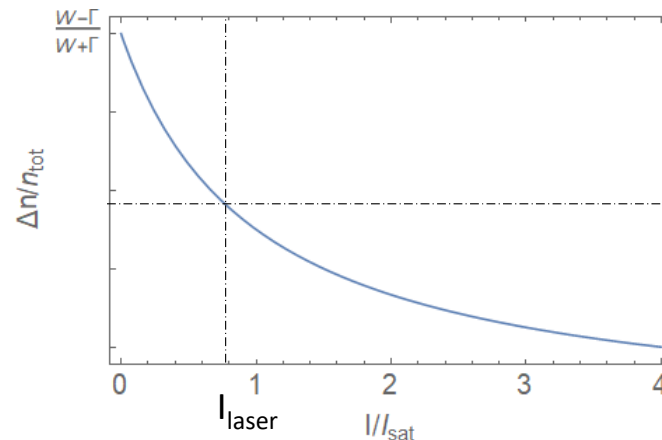
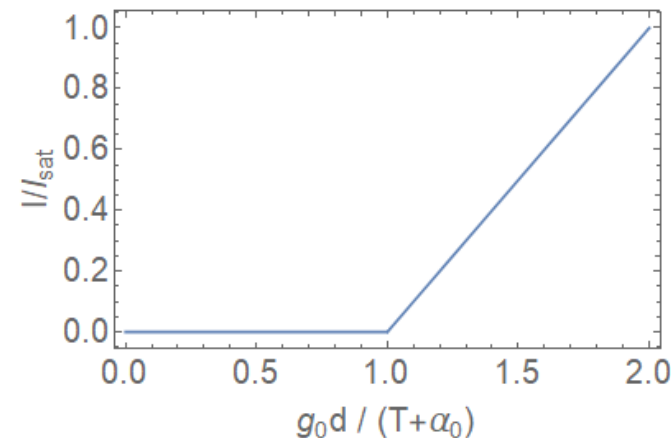
Population inversion

$$\Delta n = \frac{g_0}{\sigma} \frac{1}{1 + I/I_{\text{sat}}}$$

$$= \frac{T + \alpha_0 L}{\sigma d}$$

Such that gain = losses

No explicit dependence on I



# Gain Switching

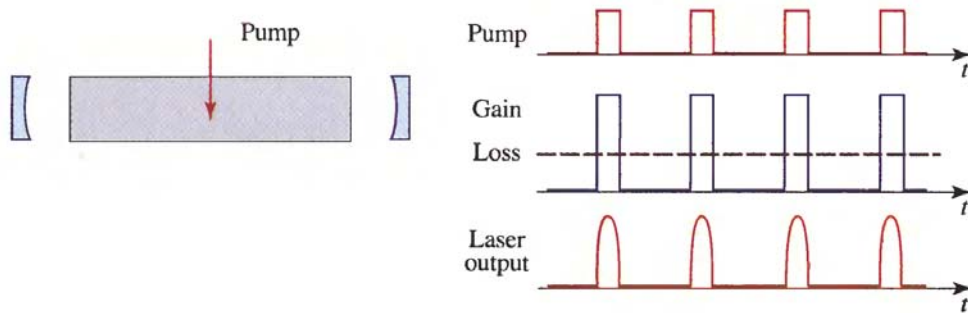


Figure 15.4-2 Gain switching.

Direct approach, involves turning « pump » on and off



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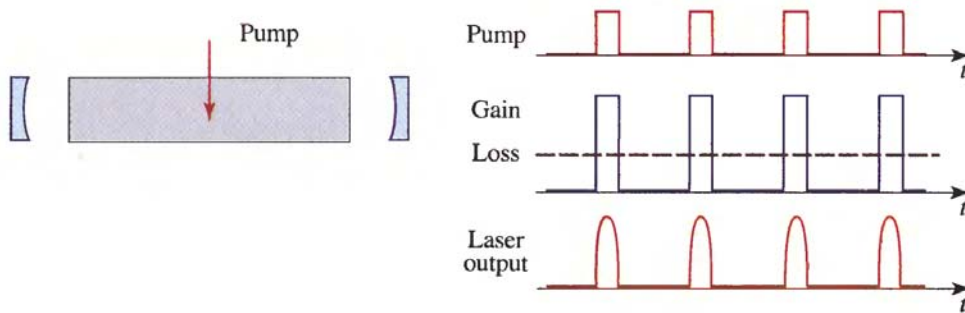
All atoms in g state  $-\sigma n_{\text{tot}} \leq g_0 \leq \sigma n_{\text{tot}}$  All atoms in e state

- Gain decreases with laser intensity

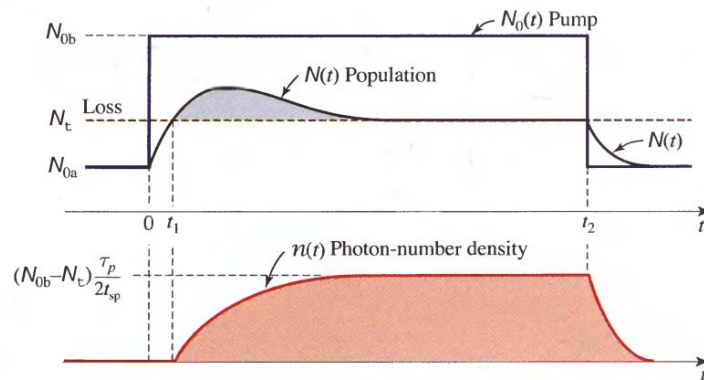
At low laser intensity,  $g = g_0$

At high laser intensity,  $g \underset{I \gg I_{\text{sat}}}{\sim} g_0 \frac{I_{\text{sat}}}{I} \rightarrow 0$

# Gain Switching



**Figure 15.4-2** Gain switching.



**Figure 15.4-5** Variation of the population difference  $N(t)$  and the photon-number density  $n(t)$  with time, as a square pump results in  $N_0$  suddenly increasing from a low value  $N_{0a}$  to a high value  $N_{0b}$ , and then decreasing back to a low value  $N_{0a}$ .

Direct approach, involves turning « pump » on and off

Inversion builds up, overcomes loss, and lasing stabilises population

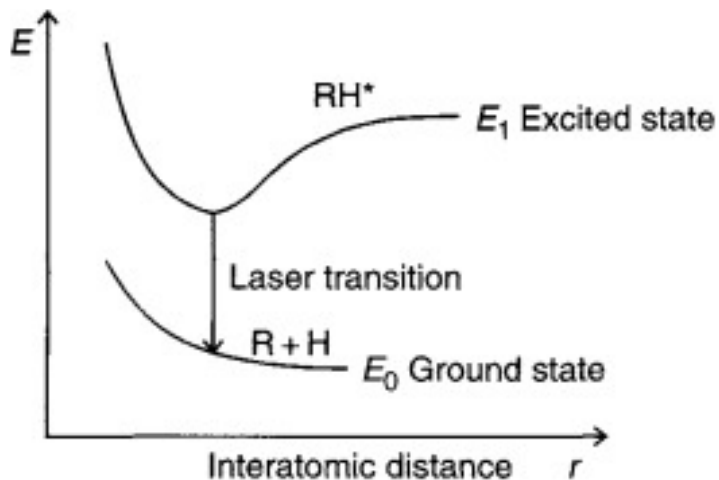
This is essentially what is being done in semiconductor laser diodes, but without fully shutting off current (small signal, to keep linearity)

# Example: Excimer (exciplex) lasers

Formation of excited dimer (excimer) or excited complex (exciplex) states driven by an pulsed electrical discharge through a gas.

These states are only stable when excited, and dissociate upon relaxation.

Helpful to create population inversion.

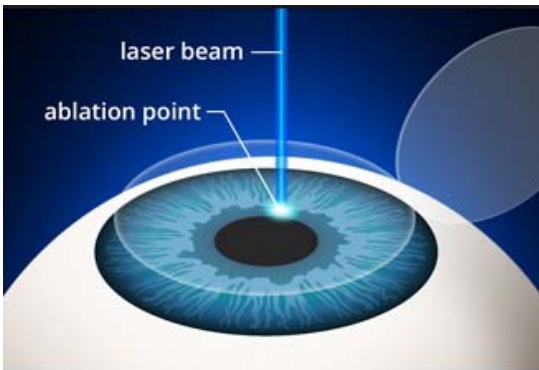


Excimer	Wavelength	Relative power
Ar <sub>2</sub> <sup>*</sup>	126 nm	
Kr <sub>2</sub> <sup>*</sup>	146 nm	
F <sub>2</sub> <sup>*</sup>	157 nm	
Xe <sub>2</sub> <sup>*</sup>	172 & 175 nm	
ArF	193 nm	60
KrCl	222 nm	25
KrF	248 nm	100
XeBr	282 nm	
XeCl	308 nm	50
XeF	351 nm	45

Equivalent to gain switching  
Results in 10 nanosecond length pulses

UV emission helpful for absorption in surface layers

# Example: Excimer (exciplex) lasers



- 4 An excimer laser reshapes the cornea with a process called photo-ablation. A small amount of corneal stroma is vaporized by the laser without any generation of heat.

[Click to view next slide ▶](#)

Material is ablated from surface without heating surroundings

Very useful for LASIK eye surgery

Figure 1: Scanning electron microscopy of a crater formed in lens nucleus following ablation in air with the 308 nm excimer laser (60 ×).

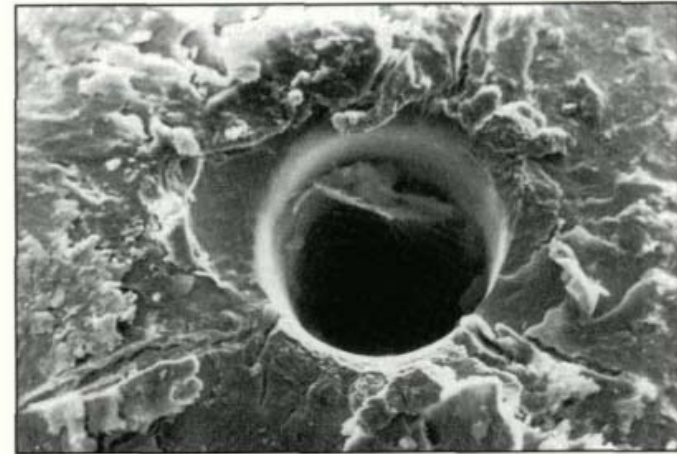


Figure 2: Scanning electron microscopy of crater formed in lens nucleus following ablation in normal saline with the 308 nm excimer laser (60 ×).



# Q Switching (Loss switching)

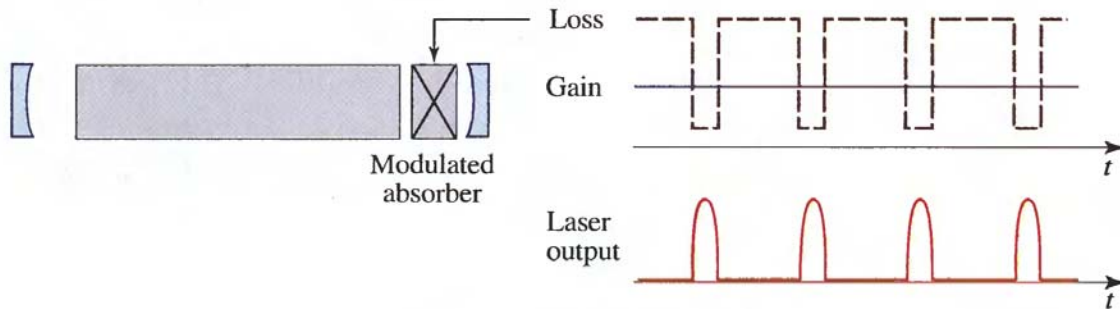


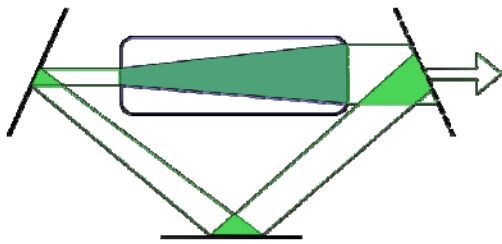
Figure 15.4-3 Q-switching.

For Q-switching, we are modulating the **loss** in the cavity

Q is the « quality » of the cavity.

Loss is first set to be high.

# III. Laser steady-state (from lecture 2)



$$|\mathcal{E}(L)| = |\mathcal{E}(0)|$$

$$r \exp(-k''d) \exp\left(-\frac{\alpha_0 L}{2}\right) = 1$$

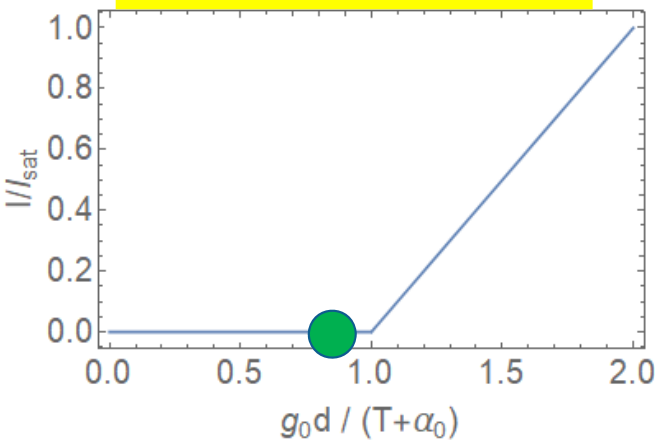
$$I(L) = I(0)$$

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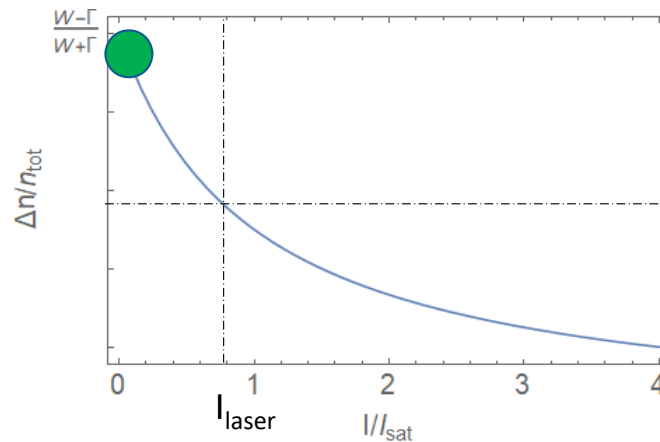
$$\Rightarrow \frac{g_0 d}{1 + I/I_{\text{sat}}} = \alpha_0 L + T$$

Laser intensity

$$I = I_{\text{sat}} \left( \frac{g_0 d}{T + \alpha_0 L} - 1 \right)$$



Population inversion



$$\Delta n = \frac{g_0}{\sigma} \frac{1}{1 + I/I_{\text{sat}}}$$

$$= \frac{T + \alpha_0 L}{\sigma d}$$

Such that gain = losses

No explicit dependence on I

# Q Switching (Loss switching)

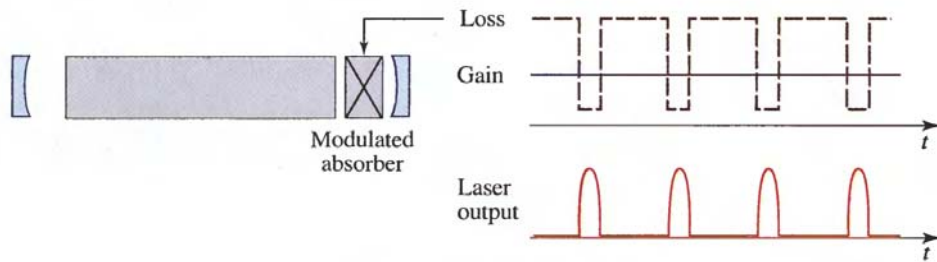


Figure 15.4-3 Q-switching.

First, loss set to be high, so inversion ( $\Delta n$ ) builds up.

Loss is then minimized, lasing begins and photon density increases

Stimulated emission depopulates excited state, lasing ends, and we start again.

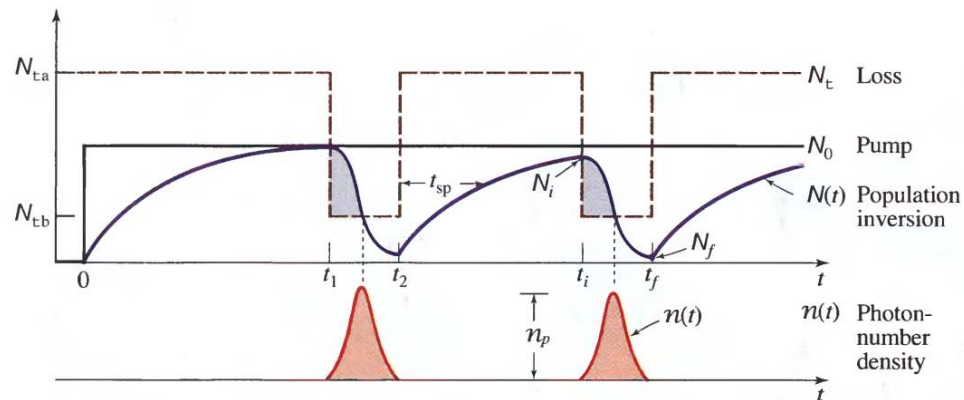
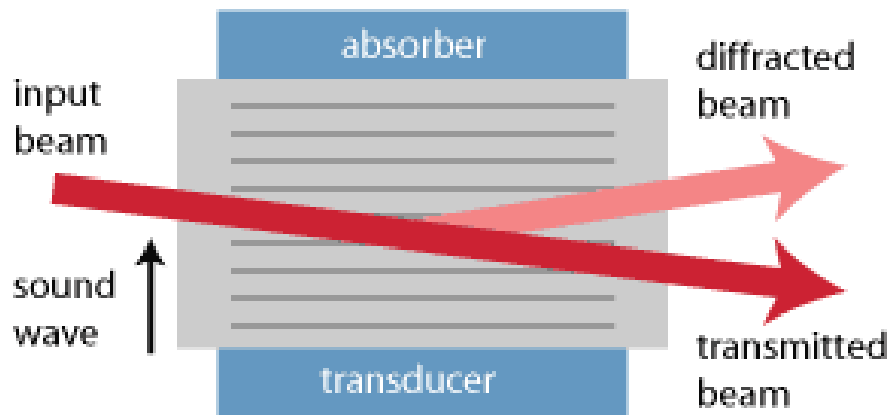


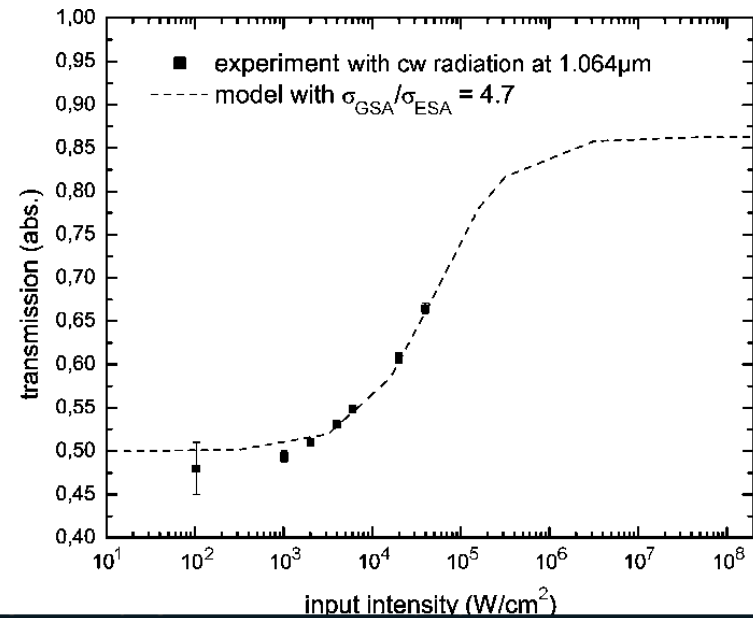
Figure 15.4-6 Operation of a Q-switched laser. Variation of the population threshold  $N_t$  (which is proportional to the resonator loss), the pump parameter  $N_0$ , the population difference  $N(t)$ , and the photon number  $n(t)$ .

# Optical switches for Q-.....switching...

## Active Q-switching: acousto-optic modulator



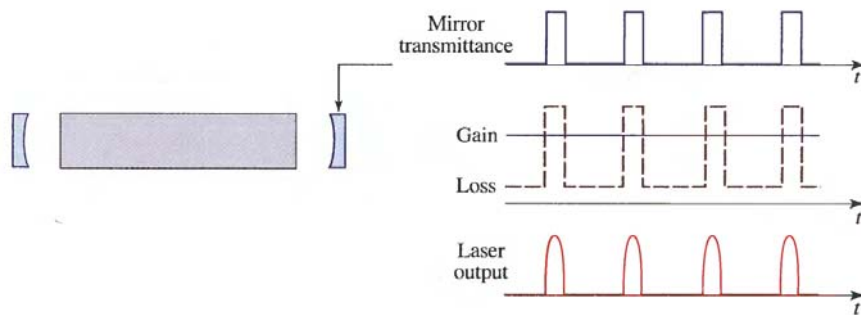
## Passive Q-switching: Saturable absorbers



Cr 4+ YAG crystal



# Cavity Dumping

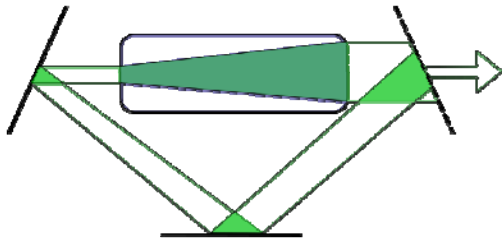


**Figure 15.4-4** Cavity dumping. One of the mirrors is removed altogether to dump the stored photons as useful light.

In cavity dumping (which is still some form of Q-switching), pulse is stored as photons (as opposed to electrons)

Initially, highly reflective mirror is used and no light is extracted.

# III. Laser steady-state (from lecture 2)



$$|\mathcal{E}(L)| = |\mathcal{E}(0)|$$

$$r \exp(-k''d) \exp\left(-\frac{\alpha_0 L}{2}\right) = 1$$

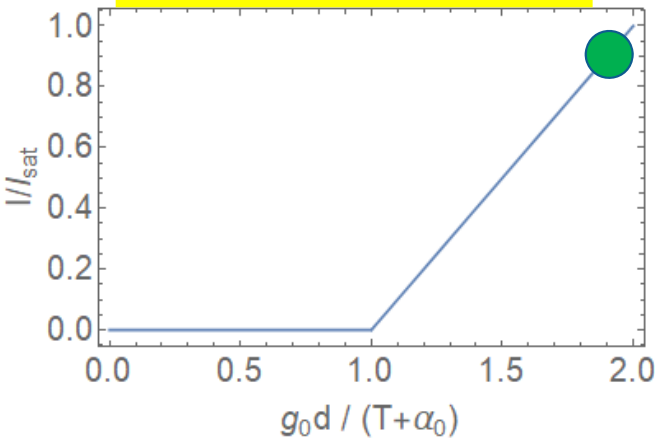
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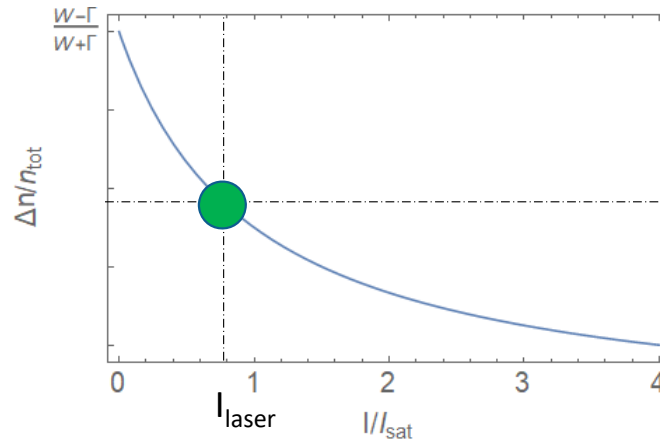
$$\Rightarrow \frac{g_0 d}{1 + I/I_{\text{sat}}} = \alpha_0 L + T$$

Laser intensity

$$I = I_{\text{sat}} \left( \frac{g_0 d}{T + \alpha_0 L} - 1 \right)$$



Population inversion



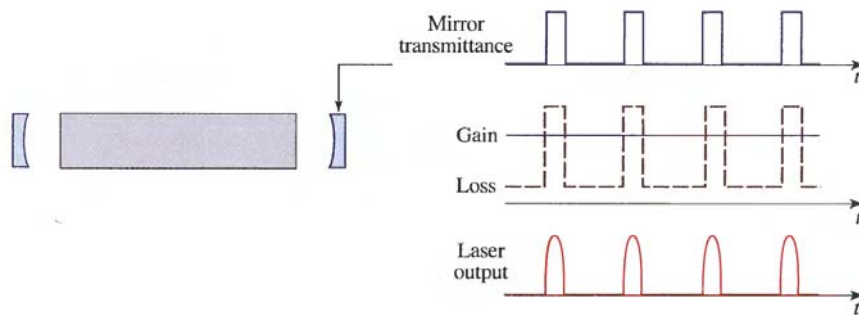
$$\Delta n = \frac{g_0}{\sigma} \frac{1}{1 + I/I_{\text{sat}}}$$

$$= \frac{T + \alpha_0 L}{\sigma d}$$

Such that gain = losses

No explicit dependence on I

# Cavity Dumping



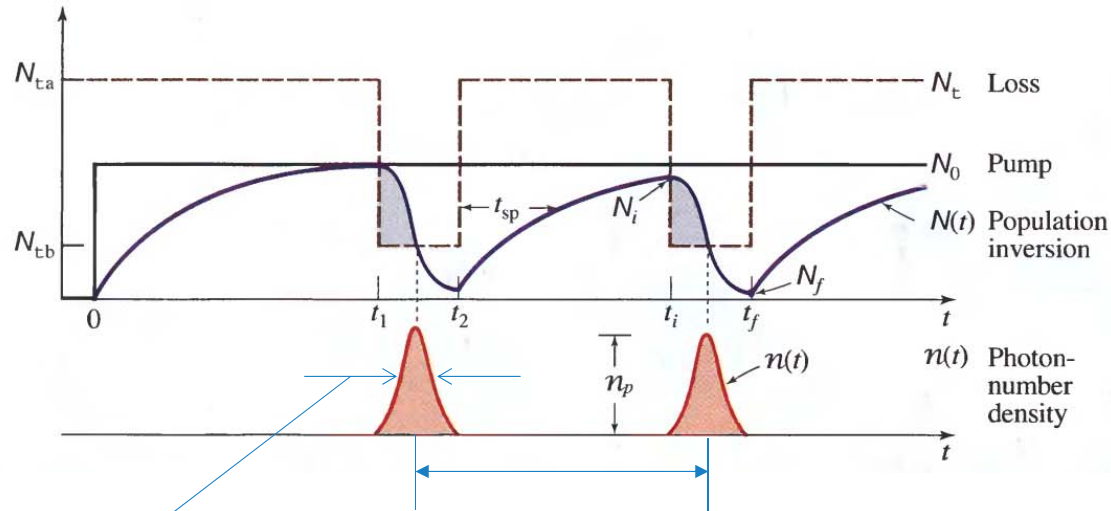
**Figure 15.4-4** Cavity dumping. One of the mirrors is removed altogether to dump the stored photons as useful light.

High reflectance mirror allows photon number to build up

Removing mirror

- Allows all accumulated photons to escape
- Removes feedback mechanism and increases loss, leading to end of lasing after photons escape

# Details on pulse trains

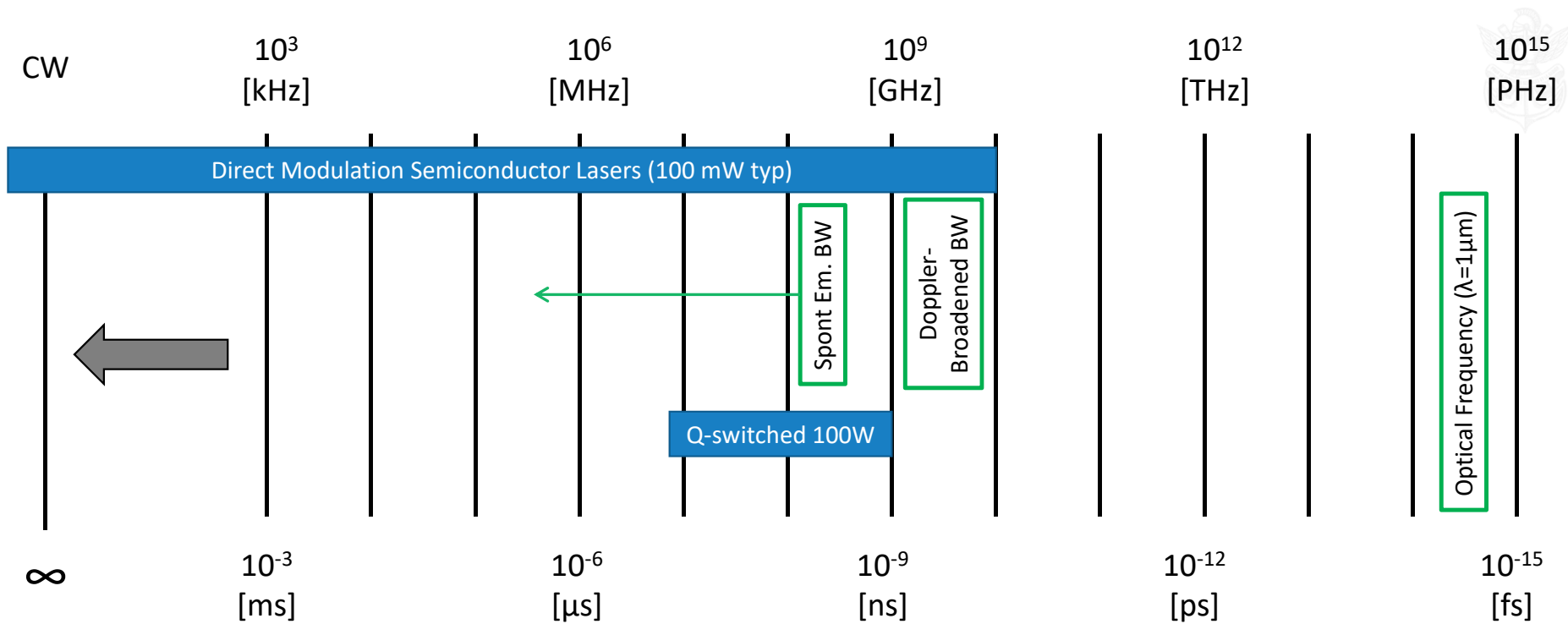


Pulse width: will be limited by how quickly we can extract stored energy. Will determine peak power/intensity.

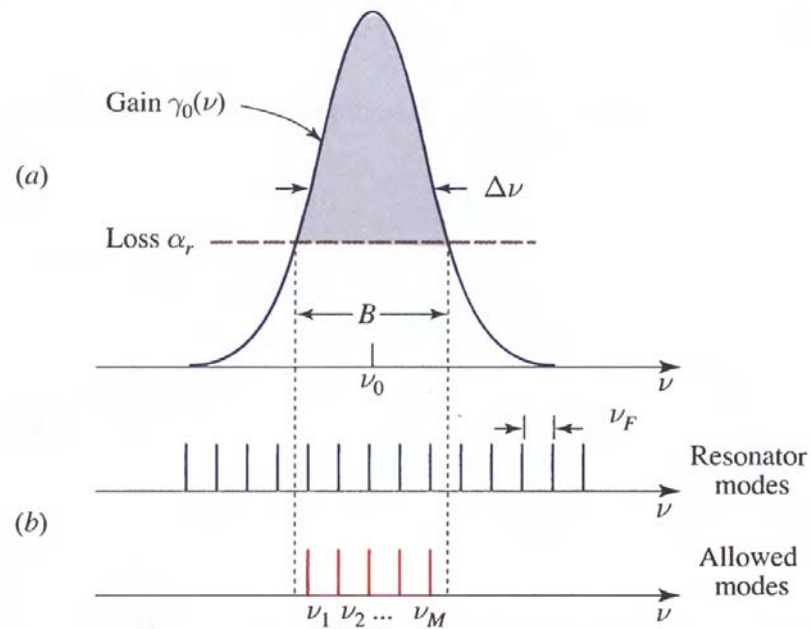
1/Repetition rate: Will be limited by how quickly energy can be built back up again.

At fixed power, will determine energy per pulse.

# Time scales for laser pulsing



# Mode Locking



Need a system where multiple longitudinal modes can lase. Each longitudinal mode has a different frequency, and allowed modes are determined by the feedback of the cavity.

# III. Mode competition (from Lecture 2)

We further increasing pumping, such that **two** modes are well above threshold

## Inhomogeneous gain :

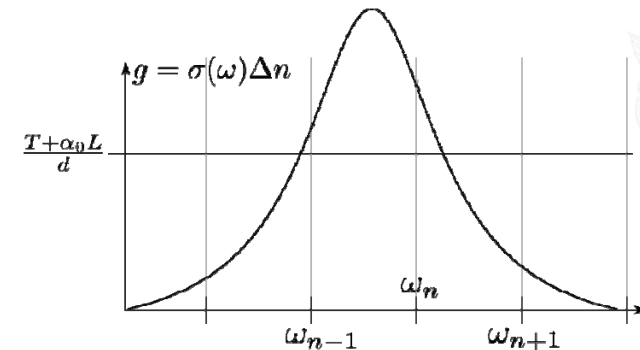
Laser intensity in 1 mode decreases gain in this mode

Modes are independent

## Homogeneous gain :

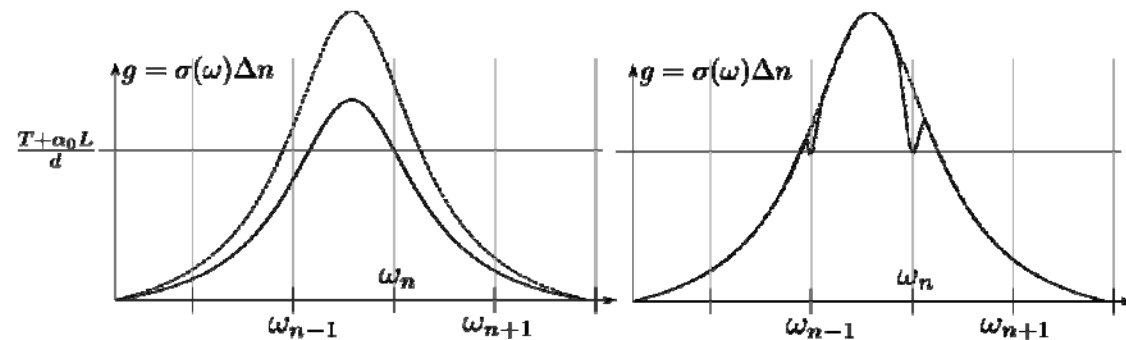
Laser intensity in 1 mode decreases gain in all modes

Mode competition !

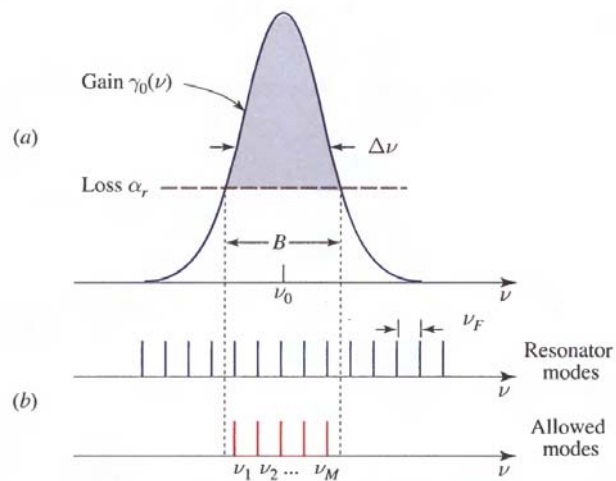


Homogenous

Inhomogenous



# Mode Locking



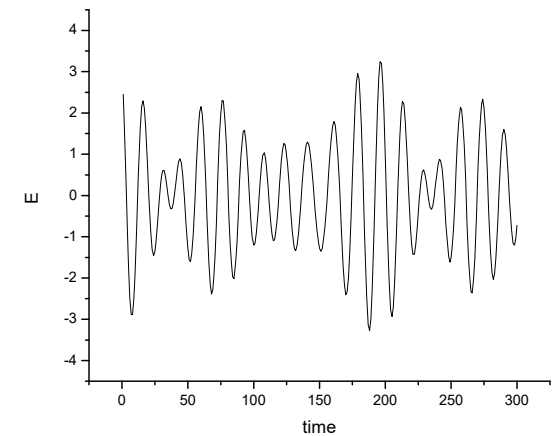
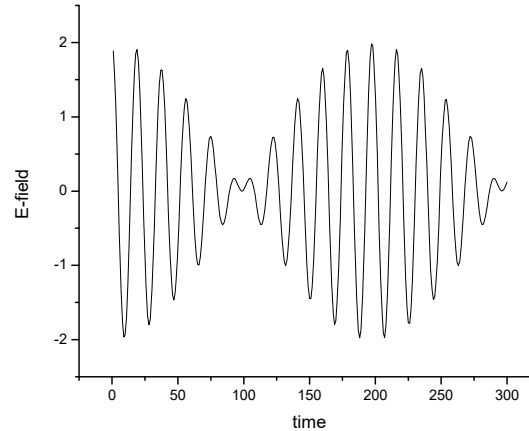
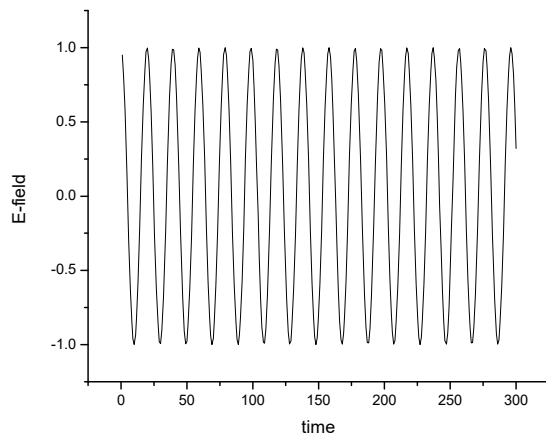
Although multiple modes may lase simultaneously, they are not coherent with each other (they have no defined phase relationship with each other).

Spontaneous emission will make modes drift around in relative phase.

The challenge is “encouraging” them to have the same phase (and so to add amplitudes at one time).

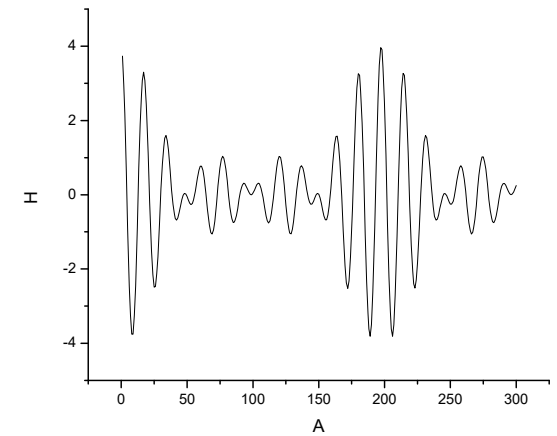
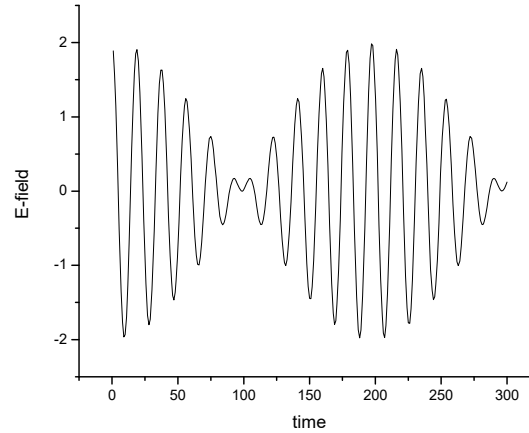
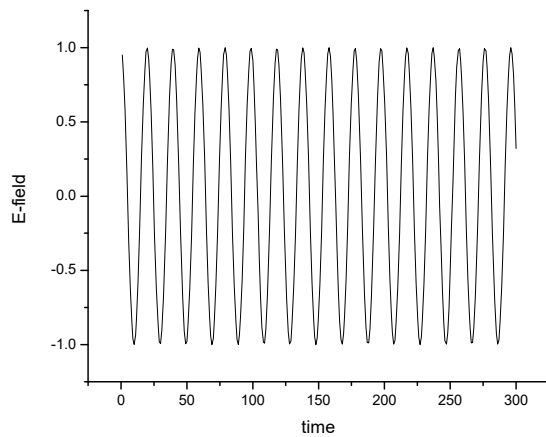


# Modes without any phase relationship



Two modes will always « beat » together.  
Beating frequency will reflect changes in phase of both modes.  
Three or more modes will make beating less evident  
SE will make modes drift around in phase – we need to “lock”  
them in when their phase is right.

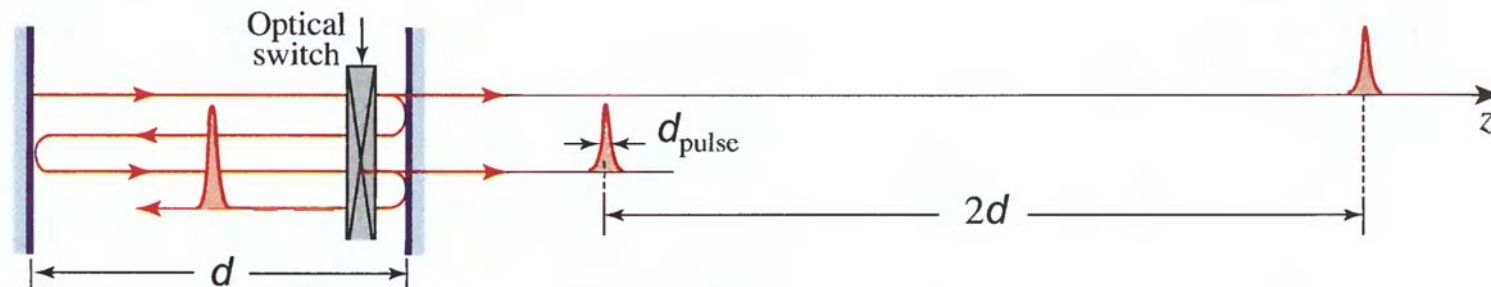
# Modes with constant phase relationship



If phase relationship is fixed between modes, then they are coherent with each other  
We can now add amplitudes and get +/- interference  
Enough modes will give a pulse train



# Mode Locking



**Figure 15.4-10** The mode-locked laser pulse reflects back and forth between the mirrors of the resonator. Each time it reaches the output mirror it transmits a short optical pulse. The transmitted pulses are separated by the distance  $2d$  and travel with velocity  $c$ . The switch opens only when the pulse reaches it and only for the duration of the pulse. The periodic pulse train is therefore unaffected by the presence of the switch. Other wave patterns, however, suffer losses and are not permitted to oscillate.

Sounds easy... so what is this switch?

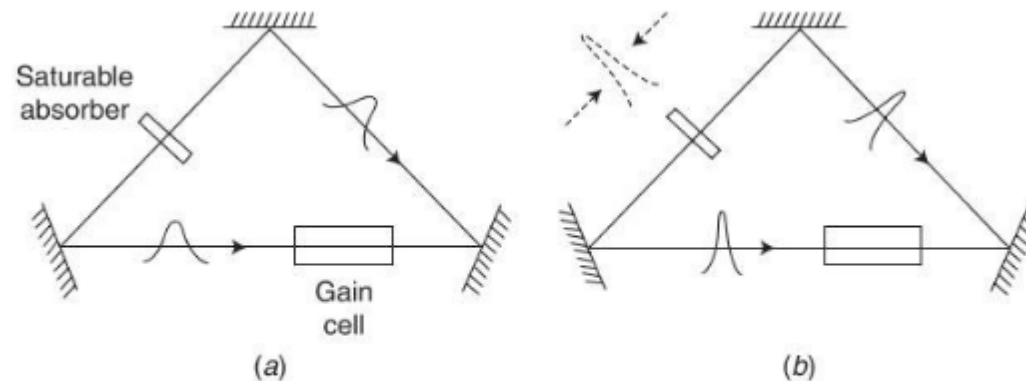
# Optical Switches – Saturable Absorber

**Active Mode Locking:** Acousto-optic or electro-optic switch, activated periodically



**Passive Mode Locking:**

- Saturable absorber (colliding-pulse ring laser)
- Non-linear optical effects (Kerr lensing:  $n=n_0+n_2I$ )



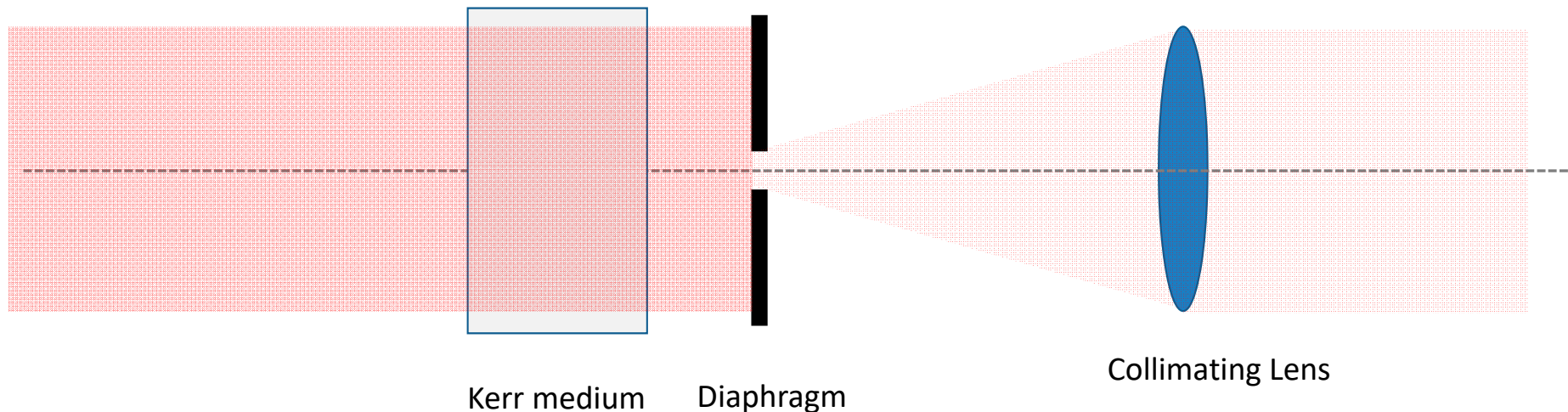
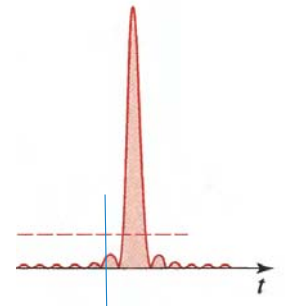
**Figure 6.17** (a) A colliding-pulse ring laser with countercirculating pulses. (b) The lowest-loss condition is for the colliding pulses to synchronize and overlap inside the thin saturable absorber.

# Optical Switches – Kerr lensing

**Active Mode Locking:** Acousto-optic or electro-optic switch, activated periodically

**Passive Mode Locking:**

- Saturable absorber
- Non-linear optical effects (Kerr lensing:  $n=n_0+n_2I$ )

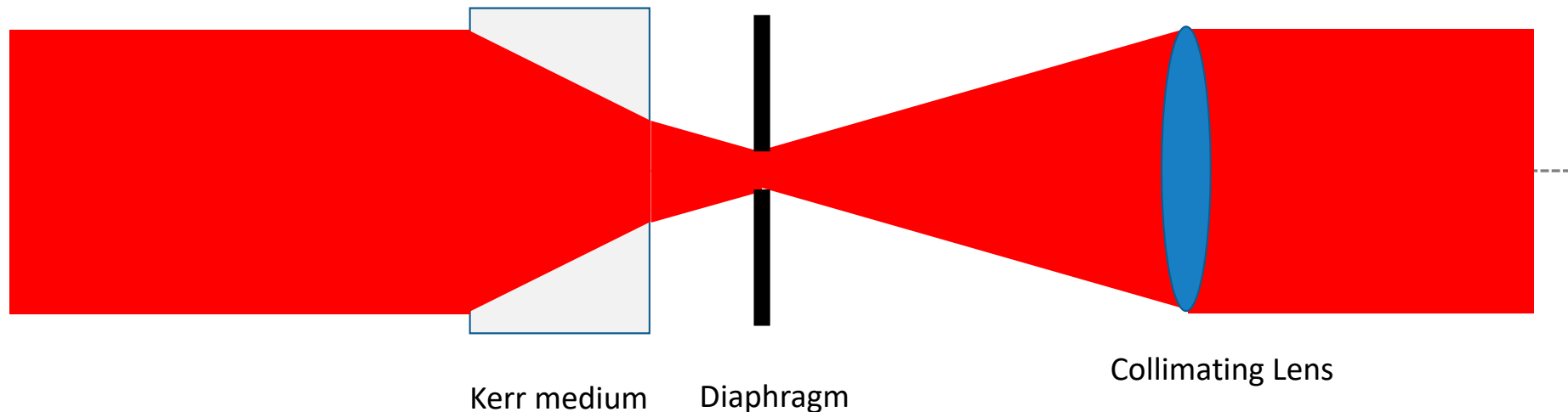
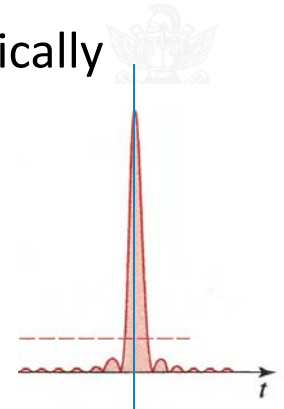


# Optical Switches – Kerr lensing

**Active Mode Locking:** Acousto-optic or electro-optic switch, activated periodically

**Passive Mode Locking:**

- Saturable absorber
- Non-linear optical effects (Kerr lensing:  $n=n_0+n_2I$ )



# Mode Locking



**Table 15.4-2** Typical pulse durations for a number of mode-locked lasers subject to homogeneous (H) and inhomogeneous (I) broadening.

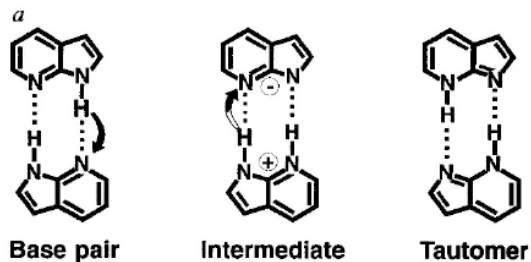
Laser Medium		Transition Linewidth <sup>a</sup> $\Delta\nu$	Calculated Pulse Duration $\tau_{\text{pulse}} = 1/\Delta\nu$	Observed Pulse Duration
Ti <sup>3+</sup> :Al <sub>2</sub> O <sub>3</sub>	H	100 THz	10 fs	10 fs
Rhodamine-6G dye	H/I	40 THz	25 fs	27 fs
Nd <sup>3+</sup> :Glass (phosphate)	I	7 THz	140 fs	150 fs
Er <sup>3+</sup> :Silica fiber	H/I	5 THz	200 fs	200 fs
Nd <sup>3+</sup> :YAG	H	150 GHz	7 ps	7 ps
Ar <sup>+</sup>	I	3.5 GHz	286 ps	150 ps
He-Ne	I	1.5 GHz	667 ps	600 ps
CO <sub>2</sub>	I	60 MHz	16 ns	20 ns

<sup>a</sup>The transition linewidths  $\Delta\nu$  are drawn from Table 14.3-1.



# Ultrashort pulse science

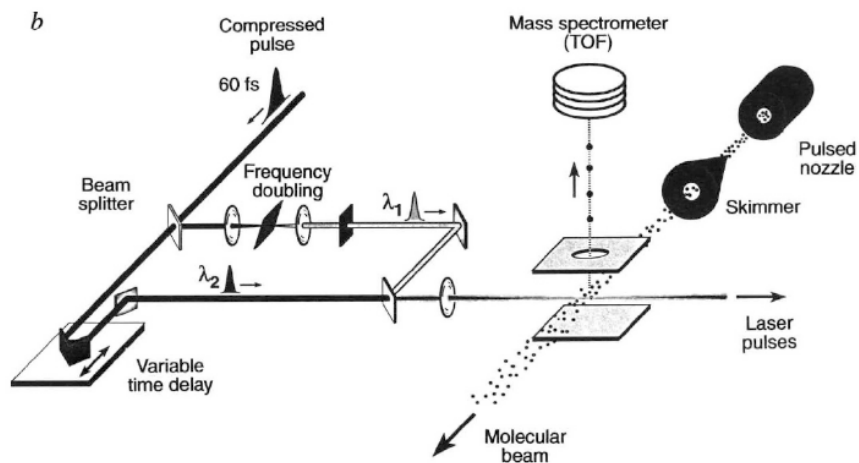
FIG. 1 a, The molecular structures involved in the two-step, or one-step, cooperative double proton transfer dynamics of the base pair (7-azaindole dimer); b, schematic diagram of part of the experimental apparatus showing the generation of the femtosecond ( $\lambda_1$ , pump;  $\lambda_2$ , probe) pulses (ref. 9, pages 120–134) and the skimmed molecular beam (ref. 9, pages 319–327), together with the detection compartment which uses time-of-flight mass spectrometry. The compressed, amplified pulses were 60 fs in duration and had an energy of  $\sim 0.5$  mJ. The cross-correlation of the pump and probe pulses was measured *in situ* to be  $\sim 150$  fs. The power of the pulses was controlled to study their effect on the transients.



## Femtosecond molecular dynamics of tautomerization in model base pairs

A. Douhal, S. K. Kim & A. H. Zewail

NATURE · VOL 378 · 16 NOVEMBER 1995



# Femtochemistry

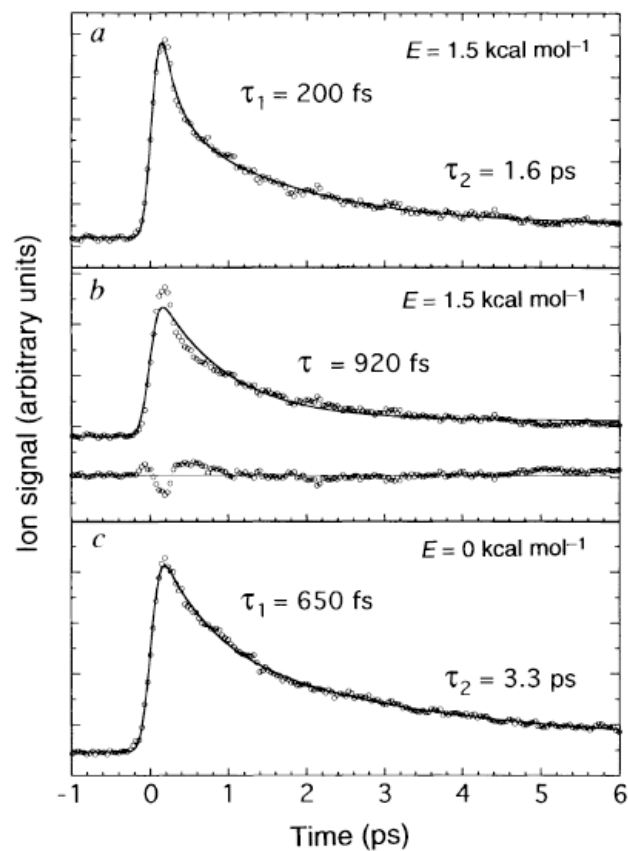
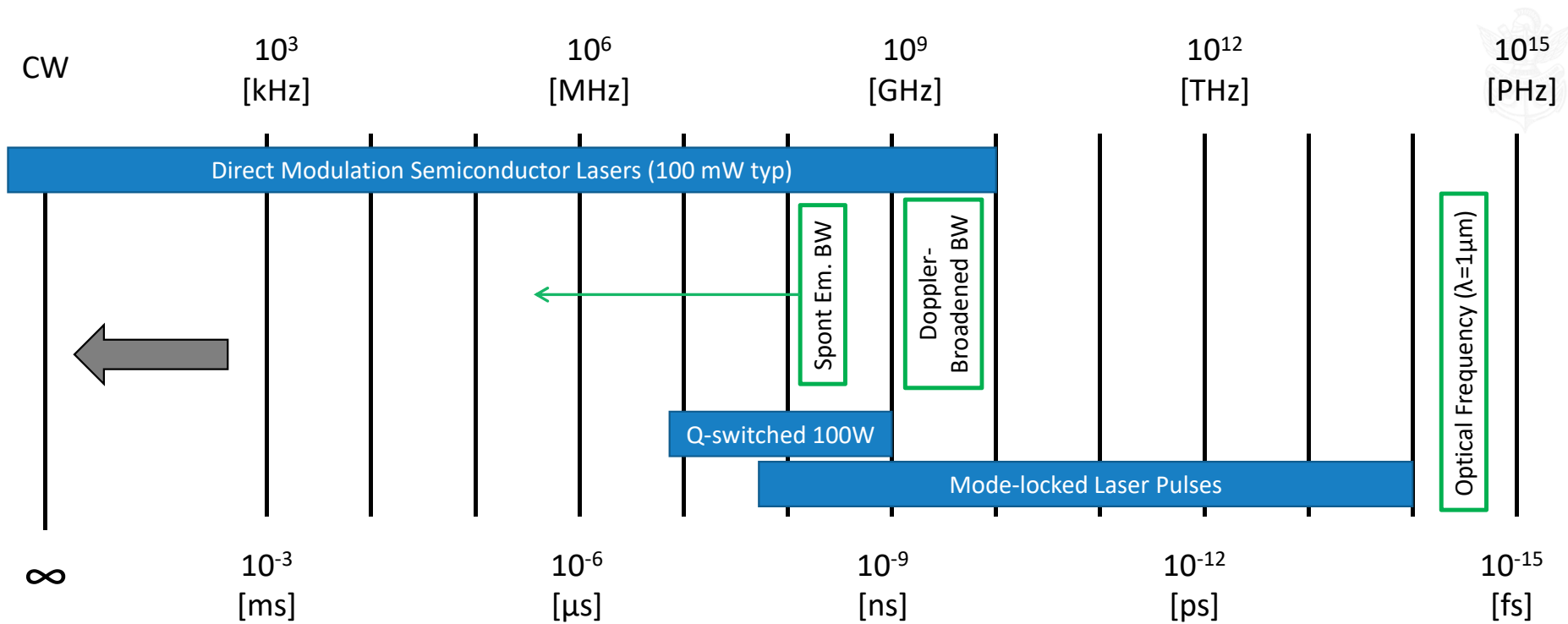


FIG. 3 Femtosecond transients of the base pair (236 AMU) as a function of the time delay. *a*, Excitation with an excess vibrational energy  $E \approx 1.5 \text{ kcal mol}^{-1}$ ; *b*, a single exponential fit of the same data; and *c*, excitation with  $E \approx 0$ . A bi-exponential function (and a small constant background) is used to fit both decays in *a* and *c*. The constant takes into account the nanosecond decay, a contribution of  $\sim 10\%$ , of the total signal. Note the distribution of residuals (lower trace) in *b* when a single exponential decay is assumed. The observed transient is not power-dependent, and only one ultraviolet photon excitation is responsible for the observed dynamics.

# Time scales for laser pulsing



# Outline of Lecture



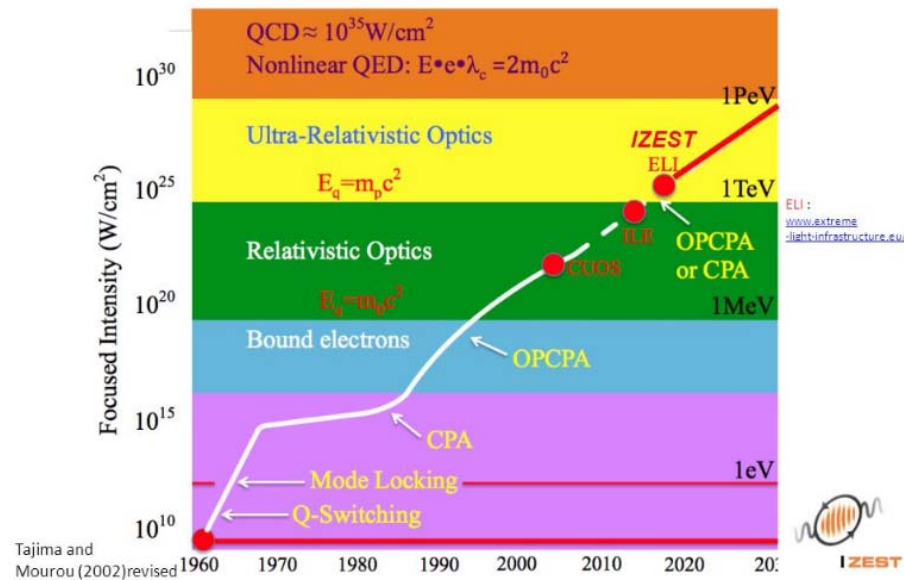
## Laser Pulsing

- I. Modulation for Telecommunications
  - Semiconductor lasers
  - Direct gain modulation
  
- II. Advanced Techniques for Shorter Pulses
  - Q-switching (and cousins)
  - Mode locking
  
- III. Even higher power
  - Chirped pulse amplification



# Pulsing for High Instantaneous Power

## Laser intensity exponentiates over years

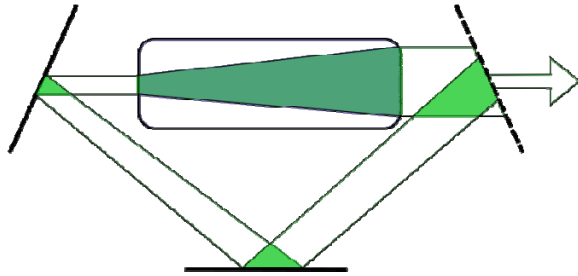


Remember, to focus perfectly, all photons must be in the same transverse mode (Lecture 3)

# Optical Amplification

An optical cavity (« oscillator ») → condition on phase

An amplifying medium (« gain ») → condition on ampl. / intensity



The saturation intensity becomes the barrier to obtaining a higher instantaneous intensity beam

Need gain to compensate losses (output + parasitic)

Impossible in Lorentz model,  
requires population inversion.

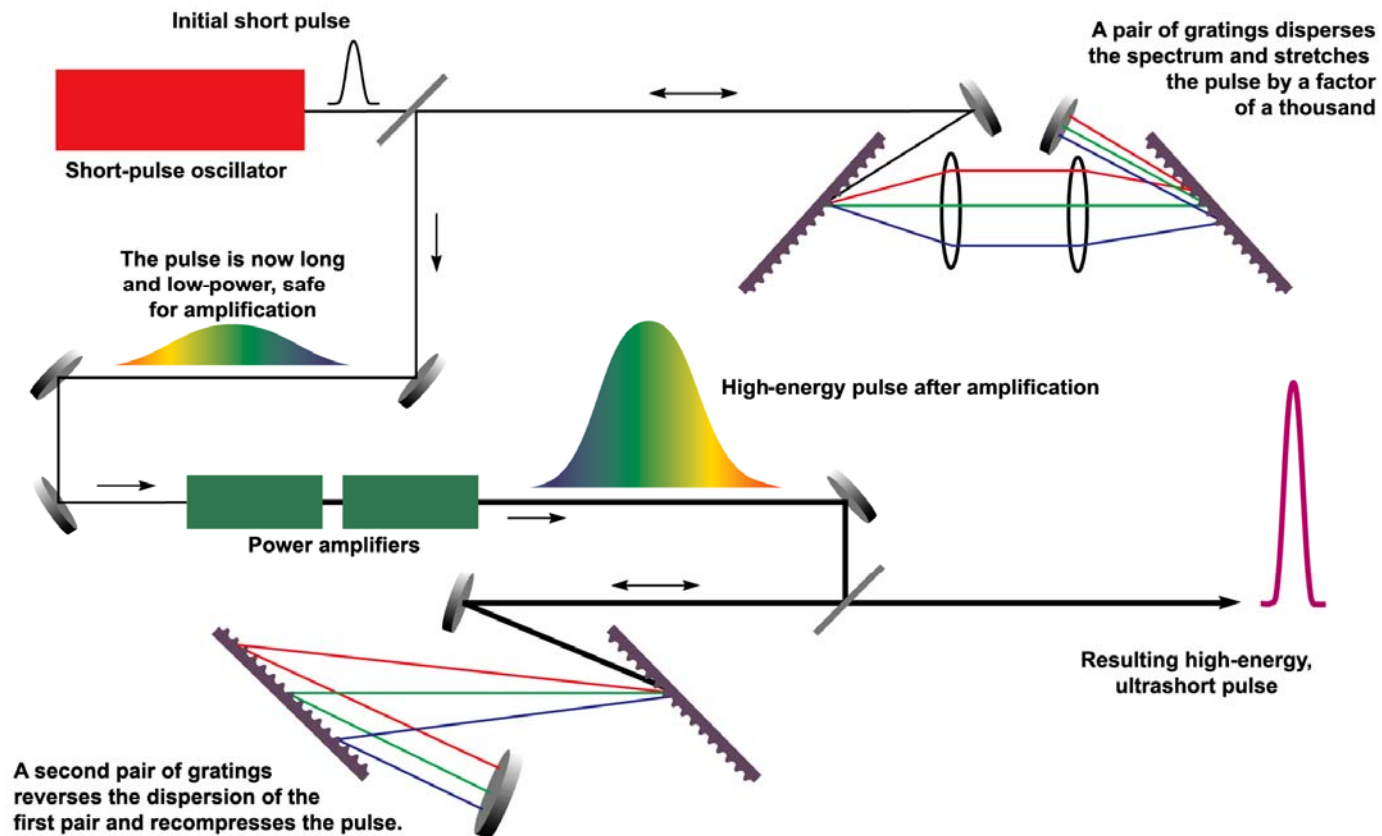
$$g = \sigma_{eg} \underbrace{(n_e - n_g)}_{\Delta n}$$

Basic laser properties

$$g = \frac{g_0}{1 + I/I_{\text{sat}}}$$

Laser threshold,  
Gain saturation,  
Steady state intensity,  
Steady state population inversion

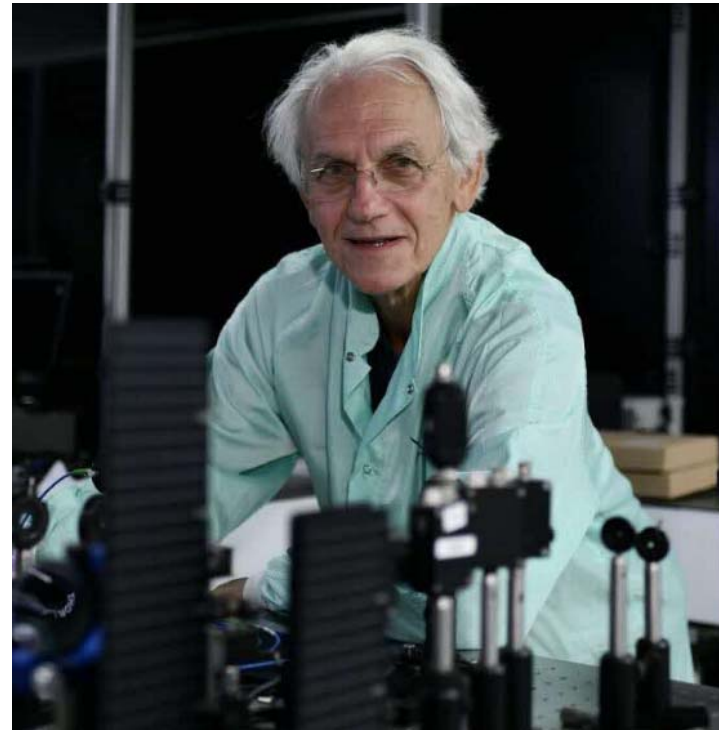
# Chirped Pulse Amplification



# 2018 Nobel Prize Winners for CPA



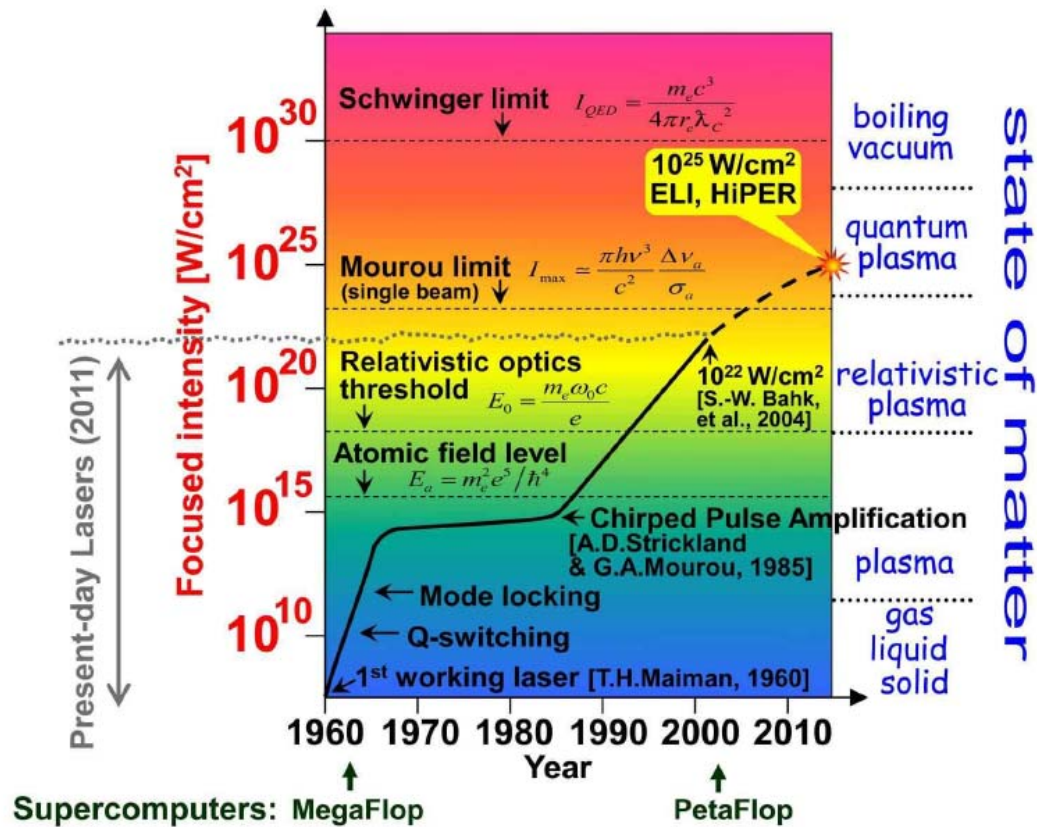
**Prof. Donna Strickland**  
University of Waterloo



**Prof. Gerard Mourou**  
Ecole Polytechnique



# Pulsing for High Instantaneous Power





# HiPER

Laser energy for the future

HOME

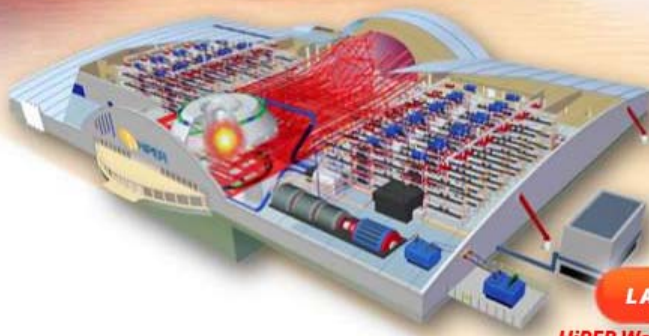
ENERGY CHALLENGE

FUSION

THE HiPER PROJECT

BENEFITS TO INDUSTRY

SCIENCE & TECHNOLOGY



LATEST NEWS

HiPER Workshop at SPIE Lasers and Optoelectronics Conference, April 2015

## The HiPER Project

HiPER, the European High Power laser Energy Research facility, is dedicated to demonstrating laser driven fusion as a future energy source.

Fusion energy will be a sustainable, environmentally clean power source using sea water as its principal source of fuel. It will produce no greenhouse gases or long-lived radioactive waste materials and will deliver energy security for the long term.

Demonstration of the scientific proof of principle for laser fusion is expected in the next couple of years at the [National Ignition Facility](#) in the USA. The HiPER Project will drive the transition from scientific proof of principle to a demonstration power plant, capable of delivering electricity to the grid.

While the primary mission of HiPER is energy, HiPER will also support a wide range of [science research](#).

PROJECT NEWS

PRESS COVERAGE

FORTHCOMING EVENTS

EVENTS ARCHIVE

PRESS CONTACT

IMAGE GALLERY

APPOINTMENTS

HiPER

The HiPER video  
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	Ελληνικά		



Inertial confinement fusion (using lasers to drive fusion) saw a big push that came up short of ignition (by about a factor of 3)

See National Ignition Facility (NIF) LLNL

Since 2012, used mostly to do science (and weapons research).

See Extreme Light Infrastructure for latest project in Europe, Station of Extreme Light in China...

# Take home message



## **Aside from technology, you already knew how to pulse a laser**

- The gain/loss balance in a laser cavity is a core concept of this course (which you already knew)
- Playing with one or the other is how we get a short pulse
- Mode-locking is establishing coherence between modes (as we did for a single mode using stimulated emission and feedback)
- Chirped Pulse Amplification is just a way around  $I_{\text{sat}}$  (which you already knew about)
- So it all fits together

# References

## **Saleh & Teich, Fundamentals of Photonics**

- Chapter 14, Laser Amplifiers
- Chapter 15, Lasers
- Chapter 17, Semiconductor Photon Sources

## **Milonni & Eberly, Lasers**

